

RELIABILITY REPORT FOR MAX11081GUU+ PLASTIC ENCAPSULATED DEVICES

September 27, 2010

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

| Approved by | |
|----------------------------------|--|
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| Quality Assurance | |
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Conclusion

The MAX11081GUU+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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- I. Device Description
 - A. General

The MAX11080/MAX11081 are a battery-pack fault-monitor ICs capable of monitoring up to 12 lithium-ion (Li+) battery cells. These devices are designed to provide an overvoltage or undervoltage fault indication when any of the cells cross the user-selectable threshold for longer than the set program-delay interval. The overvoltage levels are pin selectable from +3.3V to +4.8V in 100mV increments, and have a guaranteed accuracy of ű25mV over the entire temperature range. The undervoltage level is also user selectable from +1.6V to +2.8V in 200mV increments. These levels are guaranteed to ű100mV over the entire temperature range. Undervoltage detection can be disabled as one of the user-configuration options. The MAX11080/MAX11081 have a built-in level-shifter that allows up to 31 MAX11080/MAX11081 devices to be connected in a daisy-chain fashion to reduce the number of interface signals needed for large stacks of series batteries. Each cell is monitored differentially and compared to the overvoltage and undervoltage thresholds. When any of the cells exceed this threshold for longer than the set program delay interval, the MAX11080/MAX11081 inhibit the heartbeat signal from being passed down the daisy-chain. Built-in comparator hysteresis prevents threshold chattering. The MAX11080/MAX11081 are designed to be the perfect complement to the MAX11068 high-voltage measurement IC for redundant fault-monitoring applications. These devices are offered in a 9.7mm x 4.4mm, 38-pin TSSOP package with 0.5mm pin spacing. The package is lead-free and RoHS compliant with an extended operating temperature range of -40°C to +105°C.



II. Manufacturing Information

| A. Description/Function: | 12-Channel, High-Voltage Battery-Pack Fault Monitors |
|----------------------------------|--|
| B. Process: | S45 |
| C. Number of Device Transistors: | 11398 |
| D. Fabrication Location: | California, Texas or Japan |
| E. Assembly Location: | Thailand |

June 25, 2010

F. Date of Initial Production:

III. Packaging Information

| A. Package Type: | 38-pin TSSOP |
|---|--------------------------|
| B. Lead Frame: | Copper |
| C. Lead Finish: | 100% matte Tin |
| D. Die Attach: | Conductive |
| E. Bondwire: | Au (1 mil dia.) |
| F. Mold Material: | Epoxy with silica filler |
| G. Assembly Diagram: | |
| H. Flammability Rating: | Class UL94-V0 |
| I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C | Level 3 |
| J. Single Layer Theta Ja: | 73°C/W |
| K. Single Layer Theta Jc: | 11°C/W |
| L. Multi Layer Theta Ja: | 63°C/W |
| M. Multi Layer Theta Jc: | 11°C/W |

IV. Die Information

| A. Dimensions: | 90 X 130 mils |
|----------------------------|---|
| B. Passivation: | Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | Al/0.5%Cu with Ti/TiN Barrier |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn) |
| F. Minimum Metal Spacing: | Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |



V. Quality Assurance Information

| Α. | Quality Assurance Contacts: | Don Lipps (Manager, Reliability Engineering) |
|----|--------------------------------|--|
| | | Bryan Preeshl (Managing Director of QA) |
| В. | Outgoing Inspection Level: | 0.1% for all electrical parameters guaranteed by the Datasheet.0.1% For all Visual Defects. |
| C. | Observed Outgoing Defect Rate: | < 50 ppm |
| D. | Sampling Plan: | Mil-Std-105D |

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \times 4340 \times 75 \times 2}$ (Chi square value for MTTF upper limit) (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV) $\lambda = 14.7 \times 10^{-9}$

x = 14.7 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim"s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the S45 Process results in a FIT Rate of 0.49 @ 25C and 8.49 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot SMZYAY004C, D/C 1012)

The CO15-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1 Reliability Evaluation Test Results

MAX11081GUU+

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES | COMMENTS |
|---------------------|--|----------------------------------|-------------|-----------------------|-----------------------|
| Static Life Test (N | Note 1) Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 75 | 0 | SMZZFA004EB, D/C 0952 |

Note 1: Life Test Data may represent plastic DIP qualification lots.